# NSN 5961-00-946-6636

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## Inclosure Material:

Metal

**Overall Length:** 

0.750 inches

# Mounting Facility Quantity:

1

# Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

# **Mounting Method:**

Threaded stud

#### **Features Provided:**

Hermetically sealed case

# **Overall Width Across Flats:**

0.875 inches

#### Thread Size:

0.312 inches

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

75.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 15.0

breakdown voltage, emitter-to-base, collector open

# **Current Rating Per Characteristic:**

Between 7.50 amperes source cutoff current and 20.00 amperes source cutoff current

# Power Rating Per Characteristic:

200.0 watts small-signal input power, common-collector

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Thread Series Designator:**

Unf

# **Terminal Type And Quantity:**

3 tab, solder lug

#### Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

No

# Fiig:

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